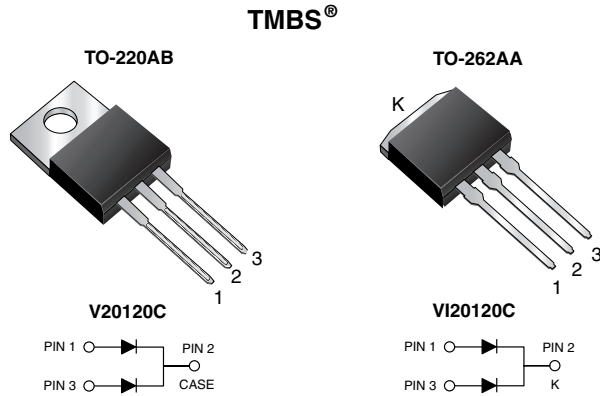


Dual High Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.54 \text{ V}$ at $I_F = 5 \text{ A}$


FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating
 Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 10 A
V_{RRM}	120 V
I_{FSM}	120 A
V_F at $I_F = 10 \text{ A}$	0.64 V
T_J max.	150 °C
Package	TO-220AB, TO-262AA
Diode variation	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V20120C	VI20120C	UNIT
Max. repetitive peak reverse voltage	V_{RRM}	120		V
Max. average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	20	A
		per diode	10	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	120		A
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150		°C



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.62	-	V
	I _F = 10 A			0.81	0.90	
	I _F = 5 A	T _A = 125 °C		0.54	-	
	I _F = 10 A			0.64	0.72	
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	8	-	μA
		T _A = 125 °C		6	-	mA
	V _R = 120 V	T _A = 25 °C		-	700	μA
		T _A = 125 °C		14	45	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V20120C	VI20120C	UNIT
Typical thermal resistance per diode	R _{θJC}	2.8		°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V20120C-M3/4W	1.88	4W	50/tube	Tube
TO-262AA	VI20120C-M3/4W	1.45	4W	50/tube	Tube
TO-220AB	V20120CHM3/4W ⁽¹⁾	1.88	4W	50/tube	Tube
TO-262AA	VI20120CHM3/4W ⁽¹⁾	1.45	4W	50/tube	Tube

Note

- (1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

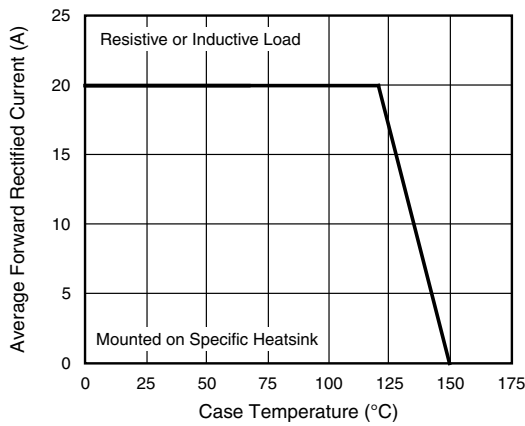


Fig. 1 - Maximum Forward Current Derating Curve

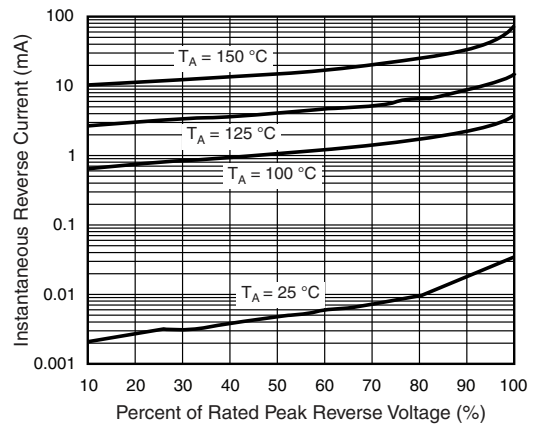


Fig. 4 - Typical Reverse Characteristics Per Diode

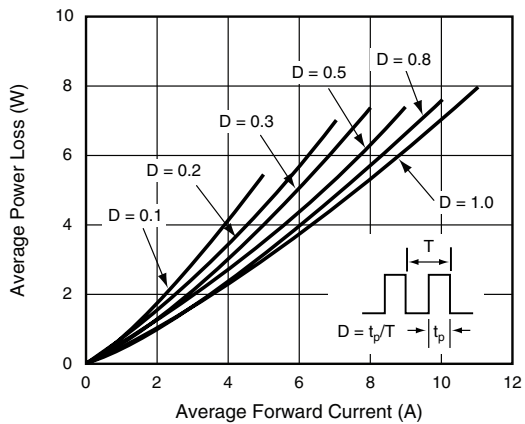


Fig. 2 - Forward Power Loss Characteristics Per Diode

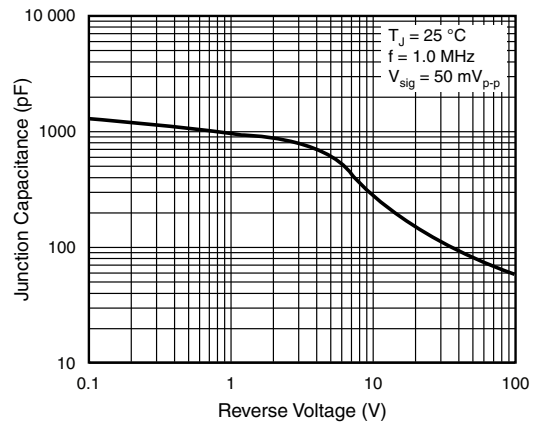


Fig. 5 - Typical Junction Capacitance Per Diode

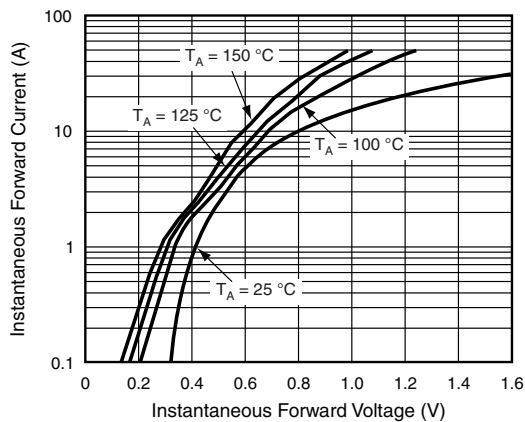


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

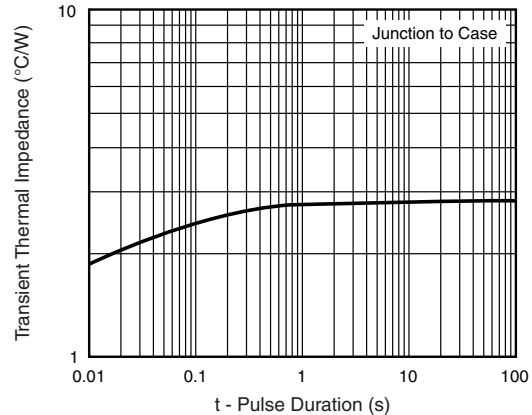
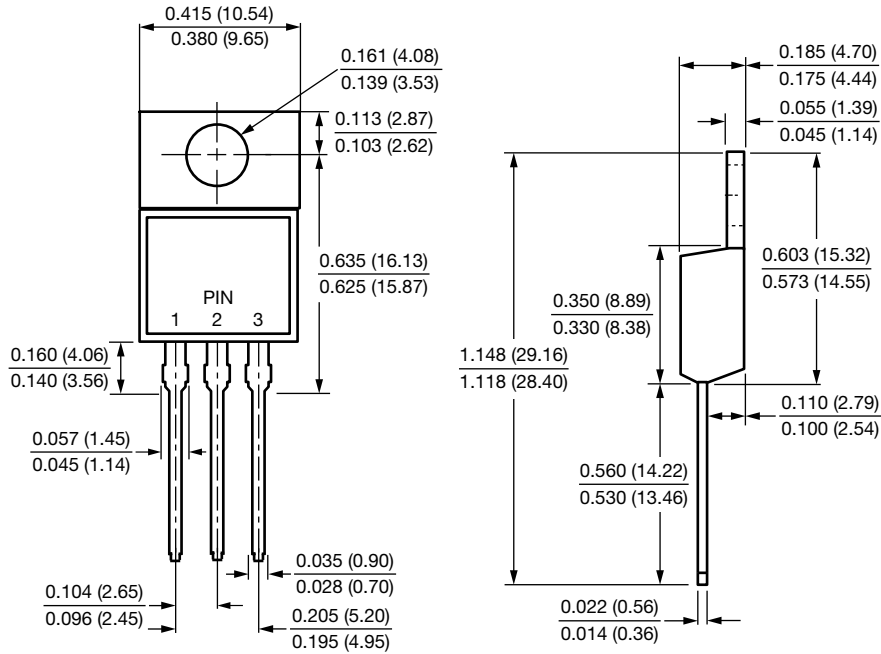


Fig. 6 - Typical Transient Thermal Impedance Per Diode

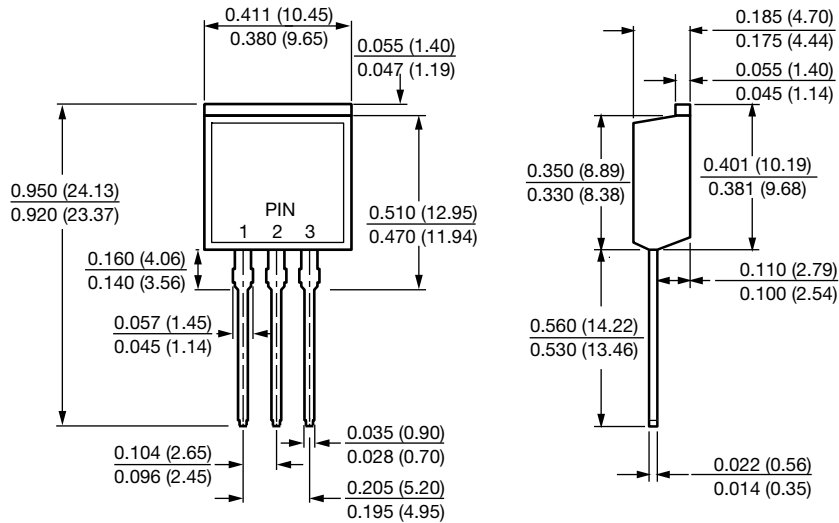


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA





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